

TOSHIBA Transistor Silicon NPN Triple Diffused Mesa Type

# 2SC5355

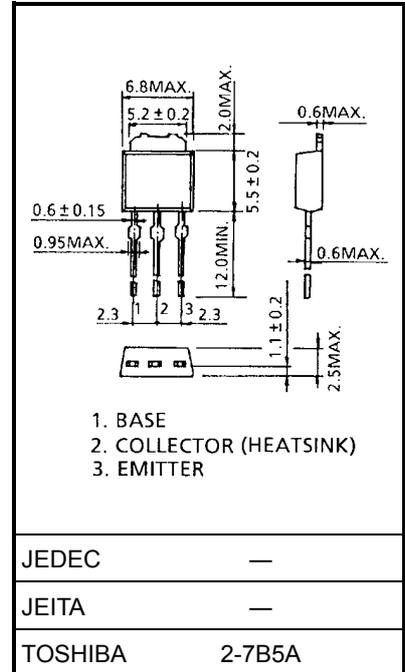
High Voltage Switching Applications  
 Switching Regulator Applications  
 DC-DC Converter Applications

- Excellent switching times:  $t_r = 0.5 \mu s$  (max),  $t_f = 0.3 \mu s$  (max)
- High collector breakdown voltage:  $V_{CEO} = 400 V$
- High DC current gain:  $h_{FE} = 20$  (min)

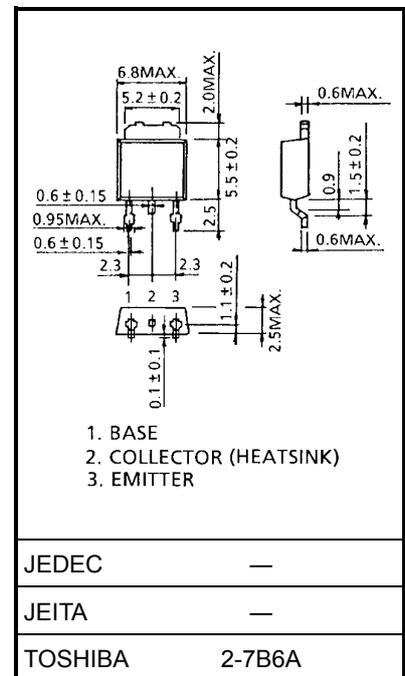
### Maximum Ratings (Ta = 25°C)

| Characteristics             |           | Symbol    | Rating  | Unit |
|-----------------------------|-----------|-----------|---------|------|
| Collector-base voltage      |           | $V_{CBO}$ | 600     | V    |
| Collector-emitter voltage   |           | $V_{CEO}$ | 400     | V    |
| Emitter-base voltage        |           | $V_{EBO}$ | 7       | V    |
| Collector current           | DC        | $I_C$     | 5       | A    |
|                             | Pulse     | $I_{CP}$  | 7       |      |
| Base current                |           | $I_B$     | 1       | A    |
| Collector power dissipation | Ta = 25°C | $P_C$     | 1.5     | W    |
|                             | Tc = 25°C |           | 25      |      |
| Junction temperature        |           | $T_j$     | 150     | °C   |
| Storage temperature range   |           | $T_{stg}$ | -55~150 | °C   |

Unit: mm



Weight: 0.36 g (typ.)

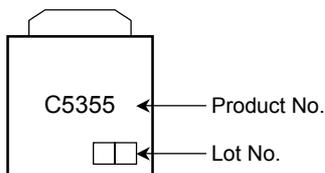


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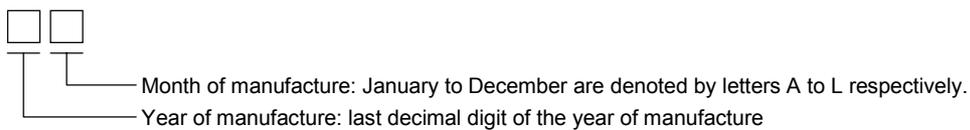
## Electrical Characteristics (Ta = 25°C)

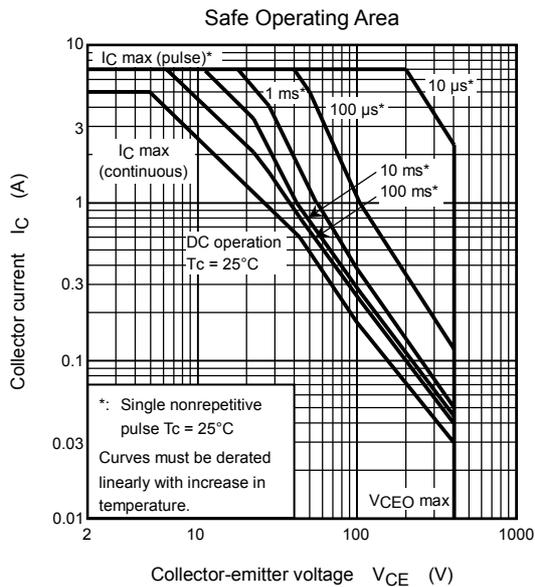
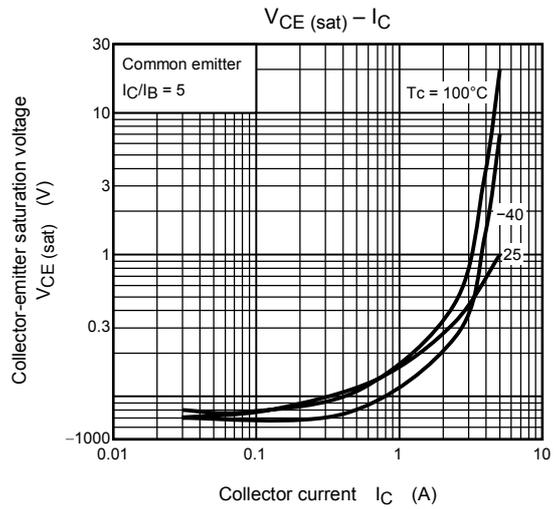
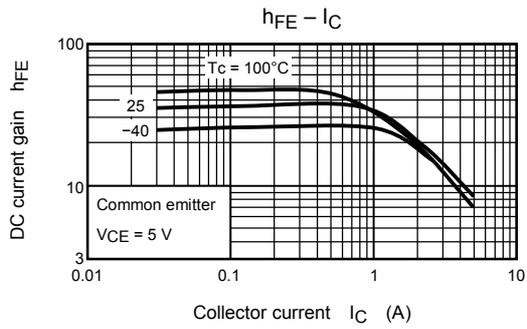
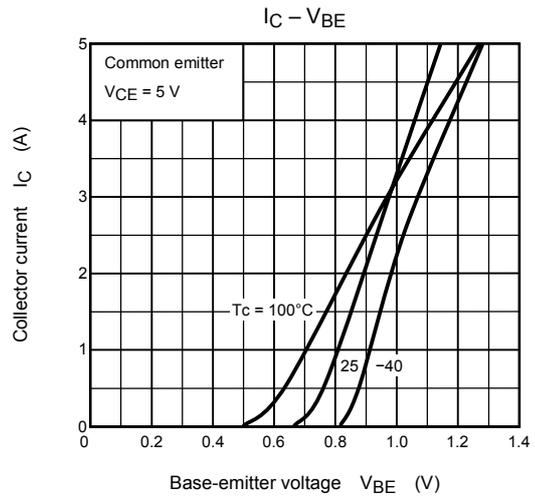
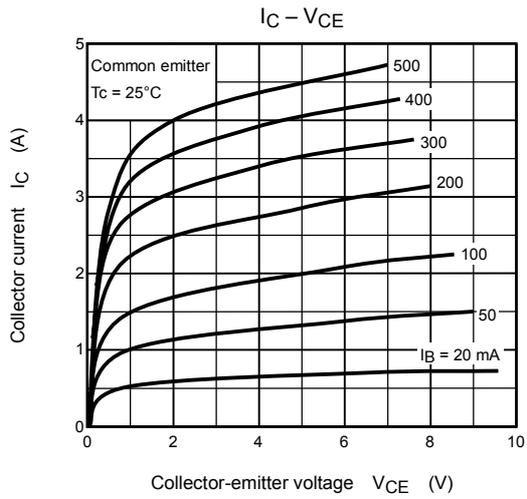
| Characteristics                      |              | Symbol         | Test Condition                              | Min   | Typ. | Max | Unit          |
|--------------------------------------|--------------|----------------|---|---|------|-----|---------------|
| Collector cut-off current            |              | $I_{CBO}$      | $V_{CB} = 480 \text{ V}, I_E = 0$           | —   | —    | 100 | $\mu\text{A}$ |
| Emitter cut-off current              |              | $I_{EBO}$      | $V_{EB} = 7 \text{ V}, I_C = 0$             | —   | —    | 10  | $\mu\text{A}$ |
| Collector-base breakdown voltage     |              | $V_{(BR) CBO}$ | $I_C = 1 \text{ mA}, I_E = 0$               | 600   | —    | —   | V             |
| Collector-emitter breakdown voltage  |              | $V_{(BR) CEO}$ | $I_C = 10 \text{ mA}, I_B = 0$              | 400   | —    | —   | V             |
| DC current gain                      |              | $h_{FE} (1)$   | $V_{CE} = 5 \text{ V}, I_C = 1 \text{ mA}$  | 12  | —    | —   |               |
|                                      |              | $h_{FE} (2)$   | $V_{CE} = 5 \text{ V}, I_C = 0.5 \text{ A}$ | 20  | —    | 65  |               |
| Collector-emitter saturation voltage |              | $V_{CE} (sat)$ | $I_C = 2 \text{ A}, I_B = 0.25 \text{ A}$   | —   | —    | 1.0 | V             |
| Base-emitter saturation voltage      |              | $V_{BE} (sat)$ | $I_C = 2 \text{ A}, I_B = 0.25 \text{ A}$   | —   | —    | 1.3 | V             |
| Switching time                       | Rise time    | $t_r$          |   | —   | —    | 0.5 | $\mu\text{s}$ |
|                                      | Storage time | $t_{stg}$      |   | —   | —    | 2.0 |               |
|                                      | Fall time    | $t_f$          |   | $I_{B1} = 0.25 \text{ A}, I_{B2} = -0.5 \text{ A}$<br>DUTY CYCLE $\leq 1\%$ | —    | —   |               |

## Marking



## Explanation of Lot No.





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